# **HEF4081B**

# **Quad 2-input AND gate**

Rev. 7 — 16 November 2011

Product data sheet

### 1. General description

The HEF4081B is a quad 2-input AND gate. The outputs are fully buffered for highest noise immunity and pattern insensitivity to output impedance variations.

It operates over a recommended  $V_{DD}$  power supply range of 3 V to 15 V referenced to  $V_{SS}$  (usually ground). Unused inputs must be connected to  $V_{DD}$ ,  $V_{SS}$ , or another input.

### 2. Features and benefits

- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Inputs and outputs are protected against electrostatic effects
- Specified from -40 °C to +85 °C and -40 °C to +125 °C
- Complies with JEDEC standard JESD 13-B

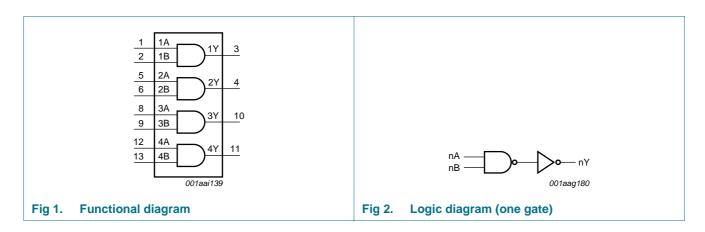
### 3. Ordering information

Table 1. Ordering information

All types operate from −40 °C to +125 °C.

| Type number | Package |  |          |  |  |  |  |  |  |
|-------------|---------|--|----------|--|--|--|--|--|--|
|             | Name    | Description  | Version  |  |  |  |  |  |  |
| HEF4081BP   | DIP14   | plastic dual in-line package; 14 leads (300 mil)           | SOT27-1  |  |  |  |  |  |  |
| HEF4081BT   | SO14    | plastic small outline package; 14 leads; body width 3.9 mm | SOT108-1 |  |  |  |  |  |  |

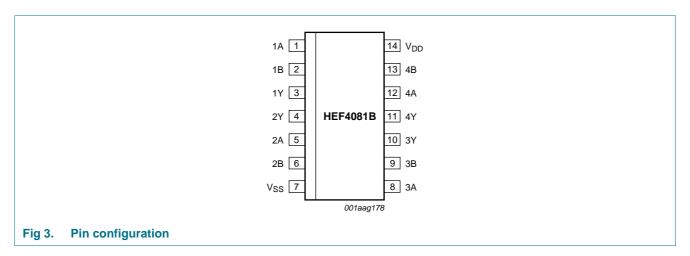
## 4. Functional diagram





# 5. Pinning information

### 5.1 Pinning



### 5.2 Pin description

Table 2. Pin description

| Symbol          | Pin          | Description    |
|-----------------|--------------|----------------|
| 1A to 4A        | 1, 5, 8, 12  | input          |
| 1B to 4B        | 2, 6, 9, 13  | input          |
| 1Y to 4Y        | 3, 4, 10, 11 | output         |
| V <sub>SS</sub> | 7            | ground (0 V)   |
| $V_{DD}$        | 14           | supply voltage |

# 6. Functional description

Table 3. Function table[1]

| Input |    | Output |  |  |  |  |
|-------|----|--------|--|--|--|--|
| nA    | nB | nY     |  |  |  |  |
| L     | L  | L      |  |  |  |  |
| L     | Н  | L      |  |  |  |  |
| Н     | L  | L      |  |  |  |  |
| Н     | Н  | Н      |  |  |  |  |

[1] H = HIGH voltage level; L = LOW voltage level.

## 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to V<sub>SS</sub> = 0 V (ground).

|                  |                         |   |              |                | -    |
|------------------|-------------------------|---|--------------|----------------|------|
| Symbol           | Parameter               | Conditions  | Min          | Max            | Unit |
| $V_{DD}$         | supply voltage          |   | -0.5         | +18            | V    |
| I <sub>IK</sub>  | input clamping current  | $V_I < -0.5 \text{ V or } V_I > V_{DD} + 0.5 \text{ V}$               | -            | ±10            | mA   |
| VI               | input voltage           |   | -0.5         | $V_{DD} + 0.5$ | V    |
| I <sub>OK</sub>  | output clamping current | $V_O < -0.5 \text{ V or } V_O > V_{DD} + 0.5 \text{ V}$               | -            | ±10            | mA   |
| I <sub>I/O</sub> | input/output current    |   | -            | ±10            | mA   |
| I <sub>DD</sub>  | supply current          |   | -            | 50             | mA   |
| T <sub>stg</sub> | storage temperature     |   | -65          | +150           | °C   |
| T <sub>amb</sub> | ambient temperature     |   | -40          | +125           | °C   |
| P <sub>tot</sub> | total power dissipation | $T_{amb} = -40  ^{\circ}\text{C} \text{ to + } 125  ^{\circ}\text{C}$ |              |                |      |
|                  |                         | DIP14   | <u>[1]</u> - | 750            | mW   |
|                  |                         | SO14  | [2] _        | 500            | mW   |
| Р                | power dissipation       | per output  | -            | 100            | mW   |
|                  |                         |   |              |                |      |

<sup>[1]</sup> For DIP14 packages: above  $T_{amb}$  = 70 °C,  $P_{tot}$  derates linearly with 12 mW/K.

### 8. Recommended operating conditions

Table 5. Recommended operating conditions

| Symbol           | Parameter                           | Conditions             | Min | Max      | Unit |
|------------------|-------------------------------------|------------------------|-----|----------|------|
| $V_{DD}$         | supply voltage                      |                        | 3   | 15       | V    |
| VI               | input voltage                       |                        | 0   | $V_{DD}$ | V    |
| T <sub>amb</sub> | ambient temperature                 | in free air            | -40 | +125     | °C   |
| Δt/ΔV            | input transition rise and fall rate | $V_{DD} = 5 V$         | -   | 3.75     | μs/V |
|                  |                                     | V <sub>DD</sub> = 10 V | -   | 0.5      | μs/V |
|                  |                                     | V <sub>DD</sub> = 15 V | -   | 0.08     | μs/V |

### 9. Static characteristics

Table 6. Static characteristics

 $V_{SS} = 0$  V;  $V_I = V_{SS}$  or  $V_{DD}$ ; unless otherwise specified.

| Symbol   | Parameter                | Conditions          | V <sub>DD</sub> | T <sub>amb</sub> = -40 °C |     | T <sub>amb</sub> = +25 °C |     | T <sub>amb</sub> = +85 °C |     | T <sub>amb</sub> = +125 °C |     | Unit |
|----------|--------------------------|---------------------|-----------------|---------------------------|-----|---------------------------|-----|---------------------------|-----|----------------------------|-----|------|
|          |                          |                     |                 | Min                       | Max | Min                       | Max | Min                       | Max | Min                        | Max |      |
| $V_{IH}$ | HIGH-level input voltage | $ I_O  < 1 \mu A$   | 5 V             | 3.5                       | -   | 3.5                       | -   | 3.5                       | -   | 3.5                        | -   | V    |
|          |                          |                     | 10 V            | 7.0                       | -   | 7.0                       | -   | 7.0                       | -   | 7.0                        | -   | V    |
|          |                          |                     | 15 V            | 11.0                      | -   | 11.0                      | -   | 11.0                      | -   | 11.0                       | -   | V    |
| $V_{IL}$ | LOW-level                | $ I_{O}  < 1 \mu A$ | 5 V             | -                         | 1.5 | -                         | 1.5 | -                         | 1.5 | -                          | 1.5 | V    |
|          | input voltage            |                     | 10 V            | -                         | 3.0 | -                         | 3.0 | -                         | 3.0 | -                          | 3.0 | V    |
|          |                          |                     | 15 V            | -                         | 4.0 | -                         | 4.0 | -                         | 4.0 | -                          | 4.0 | V    |

HEF4081B

All information provided in this document is subject to legal disclaimers.

© NXP B.V. 2011. All rights reserved.

<sup>[2]</sup> For SO14 packages: above  $T_{amb} = 70$  °C,  $P_{tot}$  derates linearly with 8 mW/K.

NXP Semiconductors HEF4081B

Quad 2-input AND gate

 Table 6.
 Static characteristics ...continued

 $V_{SS} = 0 \ V$ ;  $V_I = V_{SS}$  or  $V_{DD}$ ; unless otherwise specified.

| Symbol          | Parameter                    | Conditions                | $V_{DD}$ | T <sub>amb</sub> = | –40 °C | T <sub>amb</sub> = | +25 °C | T <sub>amb</sub> = | +85 °C | T <sub>amb</sub> = | +125 °C | Unit |
|-----------------|------------------------------|---------------------------|----------|--------------------|--------|--------------------|--------|--------------------|--------|--------------------|---------|------|
|                 |                              |                           |          | Min                | Max    | Min                | Max    | Min                | Max    | Min                | Max     |      |
| $V_{OH}$        | HIGH-level                   | $ I_O  < 1 \mu A$         | 5 V      | 4.95               | -      | 4.95               | -      | 4.95               | -      | 4.95               | -       | V    |
|                 | output voltage               |                           | 10 V     | 9.95               | -      | 9.95               | -      | 9.95               | -      | 9.95               | -       | V    |
|                 |                              |                           | 15 V     | 14.95              | -      | 14.95              | -      | 14.95              | -      | 14.95              | -       | V    |
| V <sub>OL</sub> | LOW-level                    | $ I_{O}  < 1 \mu A$       | 5 V      | -                  | 0.05   | -                  | 0.05   | -                  | 0.05   | -                  | 0.05    | V    |
|                 | output voltage               |                           | 10 V     | -                  | 0.05   | -                  | 0.05   | -                  | 0.05   | -                  | 0.05    | V    |
|                 |                              |                           | 15 V     | -                  | 0.05   | -                  | 0.05   | -                  | 0.05   | -                  | 0.05    | V    |
| I <sub>OH</sub> | HIGH-level<br>output current | $V_0 = 2.5 \text{ V}$     | 5 V      | -                  | -1.7   | -                  | -1.4   | -                  | -1.1   | -                  | -1.1    | mΑ   |
|                 |                              | V <sub>O</sub> = 4.6 V    | 5 V      | -                  | -0.64  | -                  | -0.5   | -                  | -0.36  | -                  | -0.36   | mΑ   |
|                 |                              | V <sub>O</sub> = 9.5 V    | 10 V     | -                  | -1.6   | -                  | -1.3   | -                  | -0.9   | -                  | -0.9    | mΑ   |
|                 |                              | V <sub>O</sub> = 13.5 V   | 15 V     | -                  | -4.2   | -                  | -3.4   | -                  | -2.4   | -                  | -2.4    | mΑ   |
| I <sub>OL</sub> | LOW-level                    | $V_0 = 0.4 \ V$           | 5 V      | 0.64               | -      | 0.5                | -      | 0.36               | -      | 0.36               | -       | mA   |
|                 | output current               | $V_0 = 0.5 \ V$           | 10 V     | 1.6                | -      | 1.3                | -      | 0.9                | -      | 0.9                | -       | mA   |
|                 |                              | V <sub>O</sub> = 1.5 V    | 15 V     | 4.2                | -      | 3.4                | -      | 2.4                | -      | 2.4                | -       | mA   |
| Iı              | input leakage<br>current     |                           | 15 V     | -                  | ±0.1   | -                  | ±0.1   | -                  | ±1.0   | -                  | ±1.0    | μА   |
| I <sub>DD</sub> | supply current               | all valid input           | 5 V      | -                  | 0.25   | -                  | 0.25   | -                  | 7.5    | -                  | 7.5     | μΑ   |
|                 |                              | combinations; $I_O = 0 A$ | 10 V     | -                  | 0.5    | -                  | 0.5    | -                  | 15.0   | -                  | 15.0    | μΑ   |
|                 |                              |                           | 15 V     | -                  | 1.0    | -                  | 1.0    | -                  | 30.0   | -                  | 30.0    | μΑ   |
| Cı              | input<br>capacitance         |                           |          | -                  | -      | -                  | 7.5    | -                  | -      | -                  | -       | pF   |

# 10. Dynamic characteristics

Table 7. Dynamic characteristics

 $T_{amb}$  = 25 °C; for waveforms see Figure 4; for test circuit see Figure 5; unless otherwise specified. [1]

| arrio             |                    |                |                                   |                                    | •   |     |     |      |
|-------------------|--------------------|----------------|-----------------------------------|------------------------------------|-----|-----|-----|------|
| Symbol            | Parameter          | Conditions     | $V_{DD}$                          | Extrapolation formula              | Min | Тур | Max | Unit |
| t <sub>PHL</sub>  | HIGH to LOW        | nA or nB to nY | 5 V                               | 28 ns + $(0.55 \text{ ns/pF})C_L$  | -   | 55  | 110 | ns   |
|                   | propagation delay  |                | 10 V                              | 14 ns + (0.23 ns/pF)C <sub>L</sub> | -   | 25  | 50  | ns   |
|                   |                    |                | 15 V                              | 12 ns + (0.16 ns/pF)C <sub>L</sub> | -   | 20  | 40  | ns   |
| t <sub>PLH</sub>  |                    | nA or nB to nY | 5 V                               | 18 ns + (0.55 ns/pF)C <sub>L</sub> | -   | 45  | 90  | ns   |
| propagation delay |                    | 10 V           | 9 ns + (0.23 ns/pF)C <sub>L</sub> | -                                  | 20  | 40  | ns  |      |
|                   |                    |                | 15 V                              | 7 ns + (0.16 ns/pF)C <sub>L</sub>  | -   | 15  | 30  | ns   |
| t <sub>THL</sub>  | HIGH to LOW output |                | 5 V                               | 10 ns + (1.0 ns/pF)C <sub>L</sub>  | -   | 60  | 120 | ns   |
|                   | transition time    |                | 10 V                              | 9 ns + (0.42 ns/pF)C <sub>L</sub>  | -   | 30  | 60  | ns   |
|                   |                    |                | 15 V                              | 6 ns + (0.28 ns/pF)C <sub>L</sub>  | -   | 20  | 40  | ns   |
| t <sub>TLH</sub>  | LOW to HIGH output |                | 5 V                               | 10 ns + (1.00 ns/pF)C <sub>L</sub> | -   | 60  | 120 | ns   |
|                   | transition time    |                | 10 V                              | 9 ns + (0.42 ns/pF)C <sub>L</sub>  | -   | 30  | 60  | ns   |
|                   |                    |                | 15 V                              | 6 ns + (0.28 ns/pF)C <sub>L</sub>  | -   | 20  | 40  | ns   |

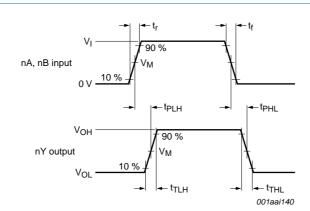
<sup>[1]</sup> The typical value of the propagation delay and output transition time can be calculated with the extrapolation formula (C<sub>L</sub> in pF).

Table 8. Dynamic power dissipation

 $V_{SS} = 0 \ V; \ t_f = t_f \le 20 \ ns; \ T_{amb} = 25 \ ^{\circ}C.$ 

| Symbol | Parameter                 | $V_{DD}$ | Typical formula  | where:   |
|--------|---------------------------|----------|--|--|
| $P_D$  | dynamic power dissipation | 5 V      | $P_D = 450 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2 (\mu W)$   | f <sub>i</sub> = input frequency in MHz;       |
|        |                           | 10 V     | $P_D = 2900 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2 (\mu W)$  | f <sub>o</sub> = output frequency in MHz;      |
|        |                           | 15 V     | $P_D = 11700 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2 (\mu W)$ | $C_L$ = output load capacitance in pF;         |
|        |                           |          |  | $\Sigma(f_0 \times C_L)$ = sum of the outputs; |
|        |                           |          |  | $V_{DD}$ = supply voltage in V.                |

### 11. Waveforms



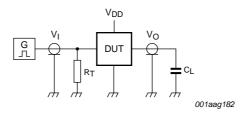
Measurement points are given in Table 9.

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig 4. Input to output propagation delay and output transition times

Table 9. Measurement points

| Supply voltage | Input              | Output             |
|----------------|--------------------|--------------------|
| $V_{DD}$       | V <sub>M</sub>     | V <sub>M</sub>     |
| 5 V to 15 V    | 0.5V <sub>DD</sub> | 0.5V <sub>DD</sub> |



Test data is given in <u>Table 10</u>.

Definitions for test circuit:

DUT = Device Under Test.

C<sub>L</sub> = load capacitance including jig and probe capacitance.

 $R_T$  = termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

Fig 5. Test circuit

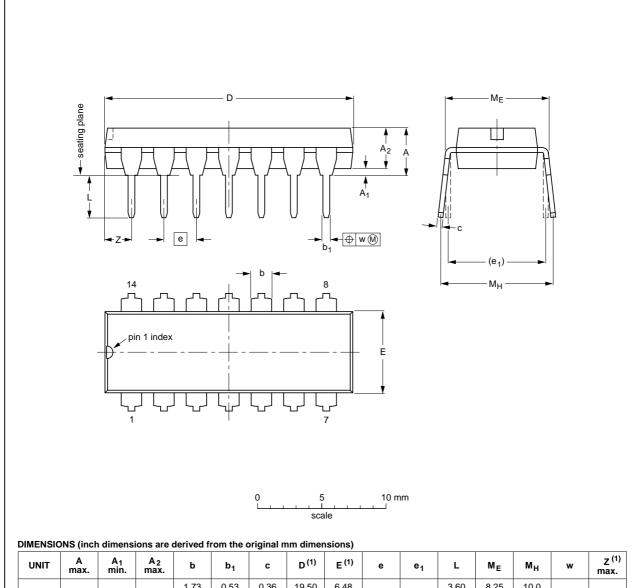
Table 10. Test data

| Supply voltage | Input                | nput I                          |       |  |  |
|----------------|----------------------|---------------------------------|-------|--|--|
| $V_{DD}$       | VI                   | t <sub>r</sub> , t <sub>f</sub> | CL    |  |  |
| 5 V to 15 V    | $V_{SS}$ or $V_{DD}$ | $\leq$ 20 ns                    | 50 pF |  |  |

# 12. Package outline

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



| UNIT   | A<br>max. | A <sub>1</sub><br>min. | A <sub>2</sub><br>max. | b              | b <sub>1</sub> | С              | D <sup>(1)</sup> | E <sup>(1)</sup> | е    | e <sub>1</sub> | L            | ME           | Мн           | w     | Z <sup>(1)</sup><br>max. |
|--------|-----------|------------------------|------------------------|----------------|----------------|----------------|------------------|------------------|------|----------------|--------------|--------------|--------------|-------|--------------------------|
| mm     | 4.2       | 0.51                   | 3.2                    | 1.73<br>1.13   | 0.53<br>0.38   | 0.36<br>0.23   | 19.50<br>18.55   | 6.48<br>6.20     | 2.54 | 7.62           | 3.60<br>3.05 | 8.25<br>7.80 | 10.0<br>8.3  | 0.254 | 2.2                      |
| inches | 0.17      | 0.02                   | 0.13                   | 0.068<br>0.044 | 0.021<br>0.015 | 0.014<br>0.009 | 0.77<br>0.73     | 0.26<br>0.24     | 0.1  | 0.3            | 0.14<br>0.12 | 0.32<br>0.31 | 0.39<br>0.33 | 0.01  | 0.087                    |

#### Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

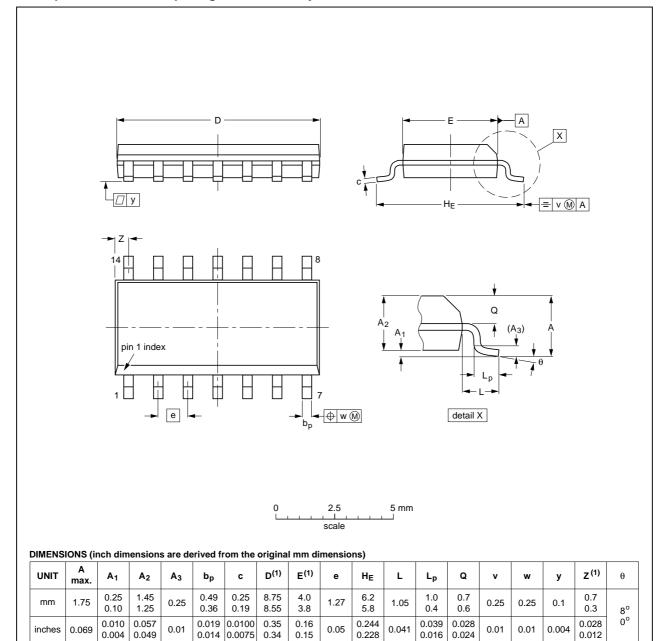
| OUTLINE | REFERENCES |        |           |  | EUROPEAN   | ISSUE DATE                      |
|---------|------------|--------|-----------|--|------------|---------------------------------|
| VERSION | IEC        | JEDEC  | JEITA     |  | PROJECTION | ISSUE DATE                      |
| SOT27-1 | 050G04     | MO-001 | SC-501-14 |  |            | <del>99-12-27</del><br>03-02-13 |

Fig 6. Package outline SOT27-1 (DIP14)

HEF4081B

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

| OUTLINE  | REFERENCES |        |       |  | EUROPEAN   | ISSUE DATE                      |
|----------|------------|--------|-------|--|------------|---------------------------------|
| VERSION  | IEC        | JEDEC  | JEITA |  | PROJECTION | 133UE DATE                      |
| SOT108-1 | 076E06     | MS-012 |       |  |            | <del>99-12-27</del><br>03-02-19 |

Fig 7. Package outline SOT108-1 (SO14)

HEF4081B

All information provided in this document is subject to legal disclaimers.

© NXP B.V. 2011. All rights reserved.

# 13. Revision history

### Table 11. Revision history

| Document ID      | Release date               | Data sheet status        | Change notice | Supersedes       |
|------------------|----------------------------|--------------------------|---------------|------------------|
| HEF4081B v.7     | 20111116                   | Product data sheet       | -             | HEF4081B v.6     |
| Modifications:   | • Table 6: I <sub>OH</sub> | minimum values changed t | o maximum     |                  |
| HEF4081B v.6     | 20091202                   | Product data sheet       | -             | HEF4081B v.5     |
| HEF4081B v.5     | 20090629                   | Product data sheet       | -             | HEF4081B v.4     |
| HEF4081B v.4     | 20080526                   | Product data sheet       | -             | HEF4081B_CNV v.3 |
| HEF4081B_CNV v.3 | 19950101                   | Product specification    | -             | HEF4081B_CNV v.2 |
| HEF4081B_CNV v.2 | 19950101                   | Product specification    | -             | -                |

### 14. Legal information

#### 14.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

#### 14.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

#### 14.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Suitability for use** — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or

malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nxp.com/profile/terms">http://www.nxp.com/profile/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

HEF4081B

NXP Semiconductors HEF4081B

#### **Quad 2-input AND gate**

Non-automotive qualified products — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

#### 14.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

### 15. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com



### 16. Contents

| 1    | General description              |
|------|----------------------------------|
| 2    | Features and benefits            |
| 3    | Ordering information             |
| 4    | Functional diagram               |
| 5    | Pinning information              |
| 5.1  | Pinning                          |
| 5.2  | Pin description                  |
| 6    | Functional description           |
| 7    | Limiting values                  |
| 8    | Recommended operating conditions |
| 9    | Static characteristics           |
| 10   | Dynamic characteristics          |
| 11   | Waveforms                        |
| 12   | Package outline                  |
| 13   | Revision history                 |
| 14   | Legal information                |
| 14.1 | Data sheet status                |
| 14.2 | Definitions                      |
| 14.3 | Disclaimers                      |
| 14.4 | Trademarks1                      |
| 15   | Contact information 1            |
| 16   | Contents                         |

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Logic Gates category:

Click to view products by NXP manufacturer:

Other Similar products are found below:

5962-8769901BCA 74HC85N NL17SG08P5T5G NL17SG32DFT2G NLU1G32AMUTCG NLV7SZ58DFT2G NLVHC1G08DFT1G
NLVVHC1G14DTT1G NLX2G08DMUTCG NLX2G08MUTCG MC74HCT20ADR2G 091992B 091993X 093560G 634701C 634921A
NL17SG32P5T5G NL17SG86DFT2G NLU1G32CMUTCG NLV14001UBDR2G NLVVHC1G132DTT1G NLVVHC1G86DTT1G
NLX1G11AMUTCG NLX1G97MUTCG 746427X 74AUP1G17FW5-7 74LS38 74LVC1G08Z-7 74LVC32ADTR2G 74LVC1G125FW4-7
74LVC08ADTR2G MC74HCT20ADTR2G NLV14093BDTR2G NLV17SZ00DFT2G NLV17SZ02DFT2G NLV17SZ126DFT2G
NLV27WZ17DFT2G NLV74HC02ADR2G NLV74HC08ADR2G NLVVHC1GT32DFT1G 74HC32S14-13 74LS133 74LVC1G32Z-7
M38510/30402BDA 74LVC1G86Z-7 74LVC2G08RA3-7 M38510/06202BFA NLV74HC08ADTR2G NLV74HC14ADR2G
NLV74HC20ADR2G